

产品概览

BC846BDW1: Dual NPN Bipolar Transistor

欲看完整文档，请参阅数据表。

The Dual NPN Bipolar Transistor is designed for general purpose amplifier applications. It is housed in the SOT-363/SC-88/SC70-6, which is designed for low power surface mount applications.

特性

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

器件电气规格

产品	Pricing (\$/Unit)	Compliance	Status	Polarity	Type	$V_{CE(sat)Max}$ (V)	I_C Cont. (A)	V_{CEO} Min (V)	V_{CBO} (V)	V_{EBO} (V)	$V_{BE(sat)}$ (V)	$V_{BE(ON)}$ (V)	h_{FE} Min	h_{FE} Max	f_T Min (MHz)	P_{TM} Max (W)	Package Type
BC846BDW1T1G	0.0264	Pb-free Halide free	Active	Dual NPN	General Purpose	0.25	0.1	65	80	6	0.7	0.66	200	450	100	0.38	SC-88-6 / SC-70-6 / SOT-363-6
SBC846BDW1T1G	0.0513	AEC Qualified PPAP Capable Pb-free Halide free	Active	Dual NPN	General Purpose	0.25	0.1	65	80	6	0.7	0.66	200	450	100	0.38	SC-88-6 / SC-70-6 / SOT-363-6

欲了解更多信息，请联系您当地的销售支援 www.onsemi.cn。

创建于：4/5/2020